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01 02 Cathode Anode

VS-8ETX06FP-N3

PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	1.4 V				
t _{rr} (typ.)	15 ns				
T _J max.	175 °C				
Package	TO-220 FullPAK 2L				
Circuit configuration	Single				

FEATURES

Hyperfast Rectifier, 8 A FRED Pt[®]

- Hyperfast recovery time
- Benchmark ultra low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 106 °C	8			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	110	А		
Repetitive peak forward current	I _{FM}		18			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage	VF	I _F = 8 A	-	2.3	3.0	V
Forward voltage V _F		I _F = 8 A, T _J = 150 °C	-	1.4	1.7	
Poweree leekeese ourrent		$V_{\rm R} = V_{\rm R}$ rated	-	0.3	50	
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	35	500	μA
Junction capacitance	CT	V _R = 600 V	-	17	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body -		8.0	-	nH

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Pb-free RoHS COMPLIANT HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	15	19	
Reverse recovery time	+	I _F = 8 A, dI _F /dt = 100 A/μs, V _R = 30 V		-	16	24	1
Reverse recovery time	t _{rr}	T _J = 25 °C		-	17	-	- ns
		T _J = 125 °C	l _F = 8 A dl _F /dt = 200 A/μs V _R = 390 V	-	40	-	
Peak recovery current		T _J = 25 °C		-	2.3	-	A
Feak recovery current	IRRM	T _J = 125 °C		-	4.5	-	
Poweree recovery charge	0	T _J = 25 °C		-	20	-	
Reverse recovery charge	everse recovery charge Q _{rr}			-	100	-	nC
Reverse recovery time	t _{rr}		I _F = 8 A	-	31	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 600 A/µs V _R = 390 V	-	12	-	А
Reverse recovery charge	Q _{rr}			-	195	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction-to-case	R _{thJC}		-	3.4	4.3	°C/W
Thermal resistance, junction-to-ambient per leg	R _{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220 FullPAK 2L 8ETX06FP				

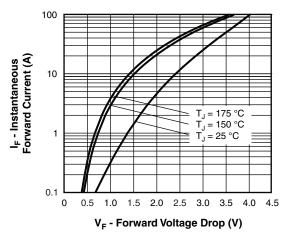


Fig. 1 - Typical Forward Voltage Drop Characteristics

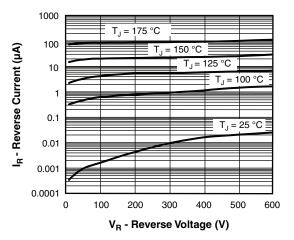


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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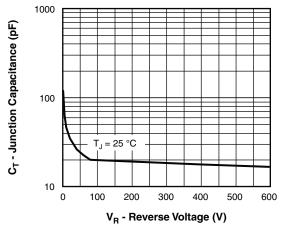


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

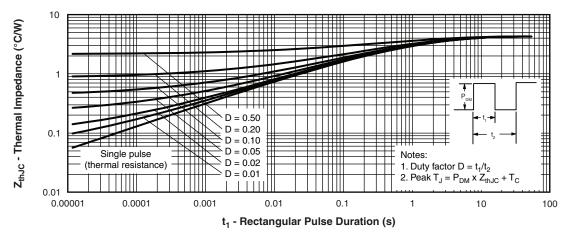
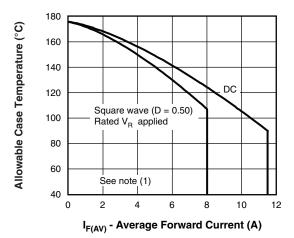
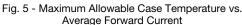


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

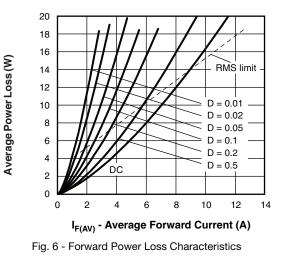






⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 5);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_{R} (1 - D); I_{R} \text{ at } V_{R1} = \text{rated } V_{R} \end{array}$



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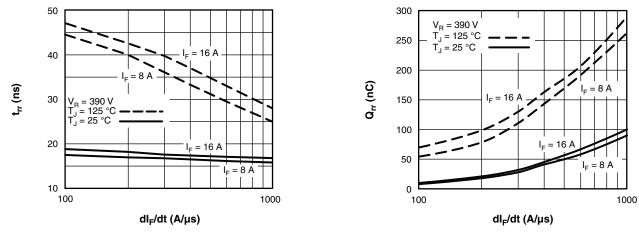


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

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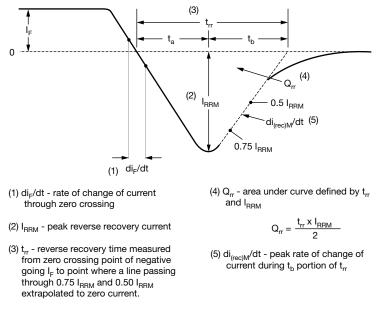


Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code	vs-	8	Е	т	х	06	FP	-N3
				-				
		2	3	4	5	6	7	8
	1	- Visł	nay Sem	nicondu	ctors pro	oduct		
	2 -	- Cur	rent rati	ng (8 =	8 A)			
	3 -	• E =	single					
	4 -	• T=	TO-220), D ² PAł	K (TO-26	53AB)		
	5 -	- X =	hyperfa	ist rectif	ier			
	6	- Volt	age rati	ng (06 =	= 600 V)			
	7 -	- FP :	= TO-22	0 FullPA	AK 2L			
	8 -			ntal digit				
		-N3	= nalog	gen-free	, Rohs-	-compli	ant, and	d totally

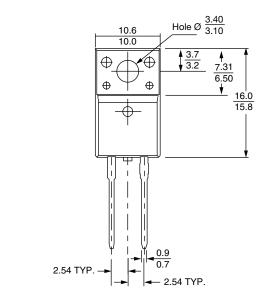
ORDERING INFORMATION (Example)								
PREFERRED P/N	ED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-8ETX06FP-N3	50	1000	Antistatic plastic tube					

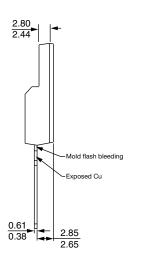
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

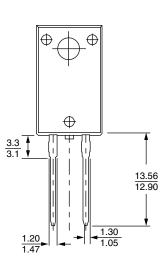


2L TO-220 FullPAK

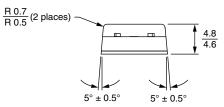
DIMENSIONS in millimeters







Bottom view





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